- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- pnp Inputs Reduce dc Loading
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

#### description

These octal buffers/drivers are designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The designer has a choice of selected combinations of inverting and noninverting outputs, symmetrical active-low output-enable ( $\overline{OE}$ ) inputs, and complementary OE and  $\overline{OE}$  inputs. These devices feature high fan-out and improved fan-in.

The -1 version of SN74ALS241C is identical to the standard version, except that the recommended maximum  $I_{OL}$  of the -1 version is 48 mA. There is no -1 version of the SN54ALS241C.

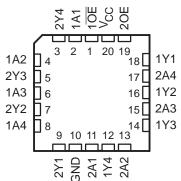
The SN54ALS241C and SN54AS241A are characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C. The SN74ALS241C and SN74AS241A are characterized for operation from 0°C to 70°C.

SN54ALS241C, SN54AS241A J PACKAGE
SN74ALS241C, SN74AS241A DW OR N PACKAGE
(TOP VIEW)

	(	,	
10E 1A1 2Y4 1A2 2Y3 1A3 2Y2 1A4	2 3 4 5 6 7 8	20 19 18 17 16 15 14 13	V <sub>CC</sub> 2OE 1Y1 2A4 1Y2 2A3 1Y3 2A2
2Y1	<b>]</b> 9	12	1Y4
2Y1 GND	9 10	12 11	] 1Y4 ] 2A1
			Г

### SN54ALS241C, SN54AS241A . . . FK PACKAGE

(TOP VIEW)



INPU	JTS	OUTPUT						
1 <mark>0E</mark>	1A	1Y						
L	Н	Н						
L	L	L						
н	Х	Z						

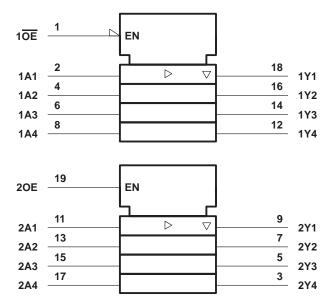
FUNCTION TABLES

INP	JTS	OUTPUT
20E	2A	2Y
н	Н	Н
н	L	L
L	Х	Z

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

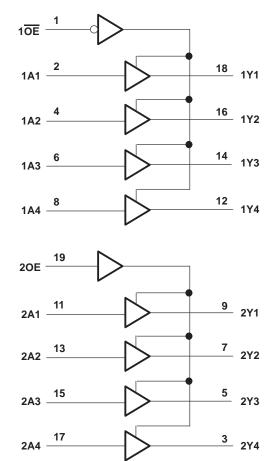
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#### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage, V <sub>CC</sub>	
Input voltage, VI	
Voltage applied to a disabled 3-state output	
Operating free-air temperature range, T <sub>A</sub> : SN54ALS241C	-55°C to 125°C
SN74ALS241C	0°C to 70°C
Storage temperature range	–65°C to 150°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



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#### recommended operating conditions

		SN54ALS241C		SN7	UNIT			
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.7			0.8	V
ЮН	High-level output current			-12			-15	mA
				12			24	mA
IOL	Low-level output current						48†	IIIA
TA	Operating free-air temperature	-55		125	0		70	°C

<sup>†</sup> Applies only to the -1 version and only if V<sub>CC</sub> is between 4.75 V and 5.25 V

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

	тгот	CONDITIONS	SN	SN54ALS241C		SN7	4ALS24	41C UNIT	
PARAMETER	IESI	T CONDITIONS		TYP‡	MAX	MIN	TYP‡	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	lj = – 18 mA			-1.2			-1.2	V
	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	$I_{OH} = -0.4 \text{ mA}$	V <sub>CC</sub> -2	2		V <sub>CC</sub> -2	2		
Vou		I <sub>OH</sub> = –3 mA	2.4	3.2		2.4	3.2		V
VOH	$V_{CC} = 4.5 V$	I <sub>OH</sub> = -12 mA	2						v
		I <sub>OH</sub> = -15 mA				2			
		I <sub>OL</sub> = 12 mA		0.25	0.4		0.25	0.4	
VOL	$V_{CC} = 4.5 V$	I <sub>OL</sub> = 24 mA					0.35	0.5	V
		I <sub>OL</sub> = 48 mA (-1 version)					0.35	0.5	
IOZH	$V_{CC} = 5.5 V,$	V <sub>O</sub> = 2.7 V			20			20	μΑ
I <sub>OZL</sub>	$V_{CC} = 5.5 V,$	$V_{O} = 0.4 V$			-20			-20	μΑ
lį	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 7 V			0.1			0.1	mA
Iн	V <sub>CC</sub> = 5.5 V,	VI = 2.7 V			20			20	μΑ
١ <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			-0.1			-0.1	mA
١O§	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-20		-112	-30		-112	mA
		Outputs high		9	17		9	18	
ICC	V <sub>CC</sub> = 5.5 V	Outputs low		15	28		15	26	mA
		Outputs disabled		17	32		17	30	

<sup>‡</sup> All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> =  $25^{\circ}$ C.

§ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.



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#### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	Сі R1 R2 Тд	= 50  pH $= 500 \Omega$ $2 = 500 \Omega$ = MIN ft	2, 2, 0 MAX <sup>†</sup>		UNIT
			SN54AL	S241C	SN74AL	S241C	
			MIN	MAX	MIN	MAX	
<sup>t</sup> PLH	А	V	3	31	2	11	ns
<sup>t</sup> PHL	A	Y	1	17	3	10	115
<sup>t</sup> PZH	1 <del>0E</del>	Y	3	33	3	21	ns
<sup>t</sup> PZL	TOE	Ŷ	3	27	4	21	115
<sup>t</sup> PHZ	1 <del>0E</del>	N N	2	17	1	10	ns
<sup>t</sup> PLZ	10E	Y	2	32	2	15	115
<sup>t</sup> PZH	205	N N	3	38	4	21	
<sup>t</sup> PZL	20E	Y	3	30	5	21	ns
<sup>t</sup> PHZ	20E	Y	2	17	2	10	ns
<sup>t</sup> PLZ	20E	ř	3	35	3	15	115

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage, V <sub>CC</sub>	
Input voltage, V <sub>1</sub>	
Voltage applied to a disabled 3-state output	
Operating free-air temperature range, T <sub>A</sub> : SN54AS241A	-55°C to 125°C
SN74AS241A	0°C to 70°C
Storage temperature range	-65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		SN54AS241A		IA	SN	UNIT		
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
IOH	High-level output current			-12			-15	mA
IOL	Low-level output current			48			64	mA
TA	Operating free-air temperature	-55		125	0		70	°C



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PARAMETER	TEST O	ONDITIONS	SN54AS241A		SN	74AS24	1A	UNIT	
	TESTO	UNDITIONS	MIN	TYP†	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT
VIK	V <sub>CC</sub> = 4.5 V,	I <sub>I</sub> = -18 mA			-1.2			-1.2	V
	$V_{CC} = 4.5 V \text{ to } 5.5 V,$	$I_{OH} = -2 \text{ mA}$	V <sub>CC</sub> -2	2		V <sub>CC</sub> -2	2		
Vari		$I_{OH} = -3 \text{ mA}$	2.4	3.4		2.4	3.4		v
VOH	$V_{CC} = 4.5 V$	I <sub>OH</sub> = -12 mA	2.4						v
		I <sub>OH</sub> = -15 mA				2.4			
Max		I <sub>OL</sub> = 48 mA		0.27	0.55				5 V
VOL	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 64 mA					0.31	0.55	
IOZH	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.7 V			50			50	μΑ
IOZL	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 0.4 V			-50			-50	μA
lj	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 7 V			0.1			0.1	mA
Чн	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 2.7 V			20			20	μA
١ <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.4 V			-1			-1	mA
IO‡	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 2.25 V	-50		-150	-50		-150	mA
		Outputs high		22	35		22	35	
ICC	V <sub>CC</sub> = 5.5 V	Outputs low		61	90		61	90	mA
		Outputs disabled		35	56		35	56	

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

<sup>‡</sup> The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current, IOS.

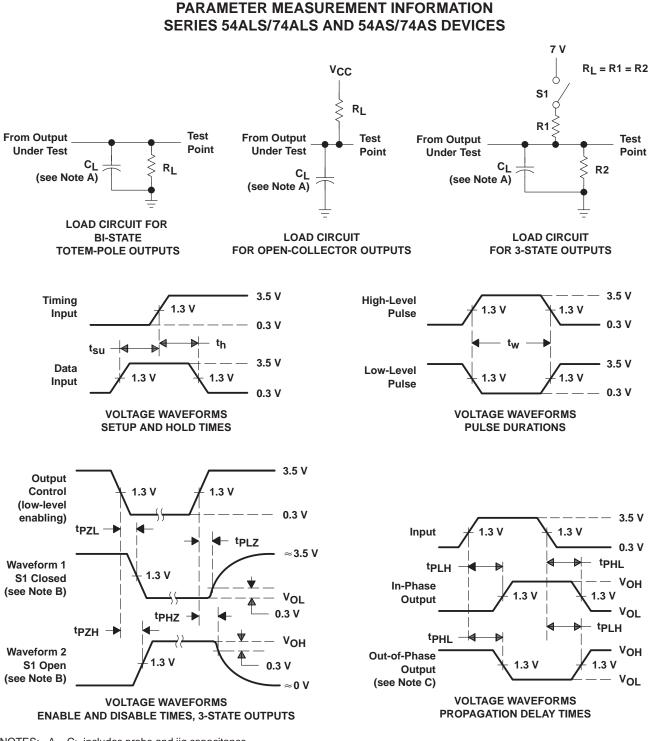
### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	F F T	$C_{L} = 50$ $R_{1} = 500$ $R_{2} = 500$ $T_{A} = MIN$	Ω, Ω, I to MAX	ş	UNIT
			SN54A		SN74A		
			MIN	MAX	MIN	MAX	
<sup>t</sup> PLH	А	Y	2	9	2	6.2	ns
<sup>t</sup> PHL		•	1	7	1	6.2	
<sup>t</sup> PZH	1 <del>0E</del>	Y	1	10	1	9	ns
tPZL	IUE	ř	2	8	2	7.5	115
<sup>t</sup> PHZ	10E	V	1	6.5	1	6	ns
<sup>t</sup> PLZ	IOE	Y	1	10.5	1	9	115
<sup>t</sup> PZH	005	V	2	11	2	10.5	ns
tPZL	20E	Y	3	9.5	3	8.5	115
<sup>t</sup> PHZ	20E	Y	1	7	1	7	00
tPLZ	20E	ſ	2	12	2	12	ns

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.



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NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics: PRR  $\leq$  1 MHz, t<sub>r</sub> = t<sub>f</sub> = 2 ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

#### Figure 1. Load Circuits and Voltage Waveforms



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